



NCE N-Channel Super Trench Power MOSFET

Description

The NCEP6080AG uses **Super Trench** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of $R_{\text{DS(ON)}}$ and Q_g . This device is ideal for high-frequency switching and synchronous rectification.

General Features

V_{DS} =60V,I_D =80A

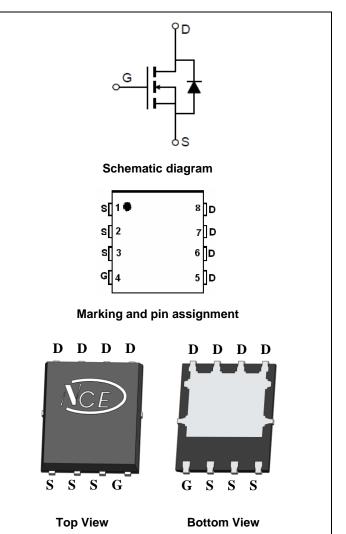
 $R_{DS(ON)} < 4.0 m\Omega$ @ $V_{GS} = 10V$ (Typ:3.5 m Ω) $R_{DS(ON)} < 5.0 m\Omega$ @ $V_{GS} = 4.5V$ (Typ:4.0 m Ω)

- Excellent gate charge x R_{DS(on)} product
- Very low on-resistance R_{DS(on)}
- 150 °C operating temperature
- Pb-free lead plating
- 100% UIS tested

Application

- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

100% UIS TESTED! 100% ΔVds TESTED!



Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP6080AG	NCEP6080AG	DFN5X6-8L	-	-	-

Absolute Maximum Ratings (T_C=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	60	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous (Silicon Limited)	I _D	80	А
Drain Current-Continuous(T _C =100°C)	I _D (100℃)	58	А
Pulsed Drain Current	I _{DM}	320	А
Maximum Power Dissipation	P _D	85	W
Derating factor		0.68	W/℃
Single pulse avalanche energy (Note 5)	E _{AS}	400	mJ
Operating Junction and Storage Temperature Range	T_{J} , T_{STG}	-55 To 150	$^{\circ}$



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NCEP6080AG

Thermal Characteristic

Thermal Resistance,Junction-to-Case ^(Note 2)	$R_{ heta JC}$	1.47	°CW	
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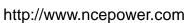
Electrical Characteristics (T_C=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics				'		•
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA	60		-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =60V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	$V_{GS}=\pm20V, V_{DS}=0V$	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	1.0	1.7	2.4	V
Dunin Course On Otata Desintana	Б.	V _{GS} =10V, I _D =40A	-	3.5	4.0	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	•	-	4.0	5.0	mΩ
Forward Transconductance	g FS	V _{DS} =10V,I _D =40A	40	-	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C _{Iss}		-	4000	-	PF
Output Capacitance	Coss	, ,	-	680	-	PF
Reverse Transfer Capacitance	C _{rss}	F=1.UIVIMZ	-	23	-	PF
Switching Characteristics (Note 4)				'		•
Turn-on Delay Time	t _{d(on)}		-	11	-	nS
Turn-on Rise Time	t _r	V_{DD} =30 V , I_D =40 A	-	5	-	nS
Turn-Off Delay Time	t _{d(off)}	$V_{GS}\text{=}10V, R_{G}\text{=}4.7\Omega$	-	56	-	nS
Turn-Off Fall Time	t _f		-	12	-	nS
Total Gate Charge	Qg	V 00V/I 40A	-	67		nC
Gate-Source Charge	Q _{gs}	$V_{DS}=30V,I_{D}=40A,$	-	12		nC
Gate-Drain Charge	Q_{gd}	V _{GS} =10V	_S =10V			nC
Drain-Source Diode Characteristics	-		•	<u>. </u>		•
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =80A	-		1.2	V
Diode Forward Current (Note 2)	Is		-	-	80	Α
Reverse Recovery Time	t _{rr}	$T_J = 25$ °C, $I_F = I_S$	-	48		nS
Reverse Recovery Charge	Qrr	$di/dt = 100A/\mu s^{(Note3)}$	-	60		nC

Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition : Tj=25 $^{\circ}\text{C}$,V_DD=30V,V_G=10V,L=0.5mH,Rg=25 Ω

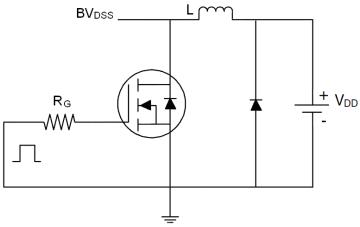
NCEP6080AG



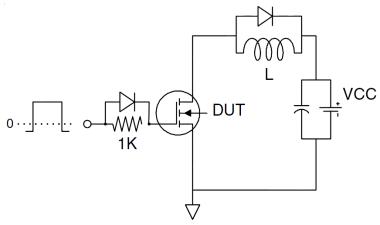


Test Circuit

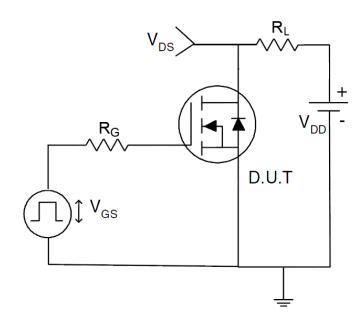
1) E_{AS} test Circuit



2) Gate charge test Circuit



3) Switch Time Test Circuit





Typical Electrical and Thermal Characteristics

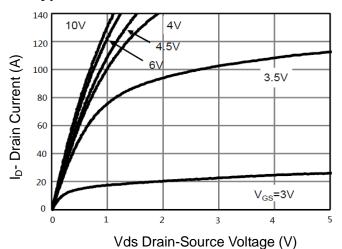


Figure 1 Output Characteristics

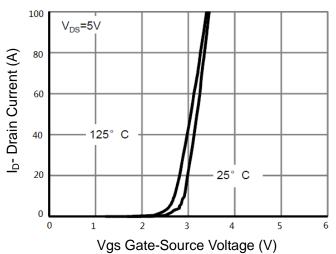


Figure 2 Transfer Characteristics

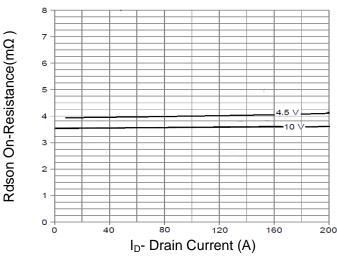


Figure 3 Rdson- Drain Current

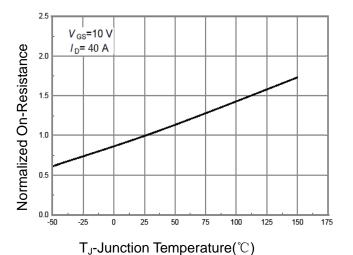


Figure 4 Rdson-JunctionTemperature

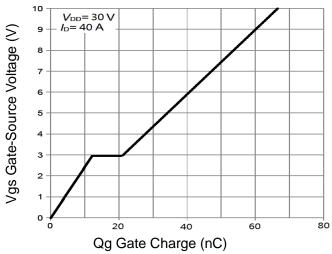


Figure 5 Gate Charge

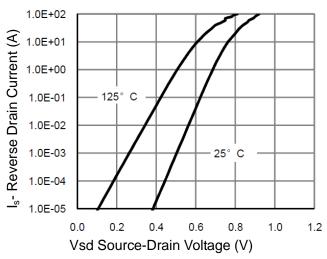


Figure 6 Source- Drain Diode Forward



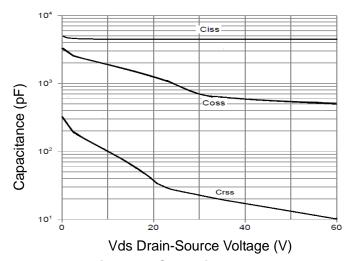


Figure 7 Capacitance vs Vds

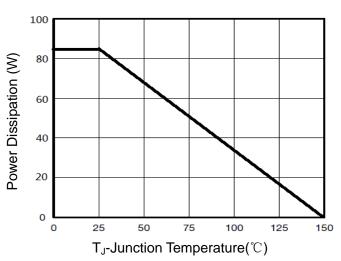


Figure 9 Power De-rating

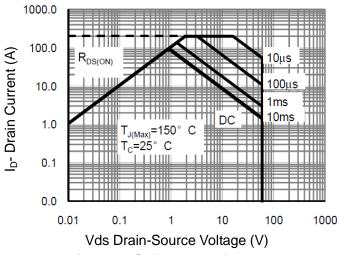


Figure 8 Safe Operation Area

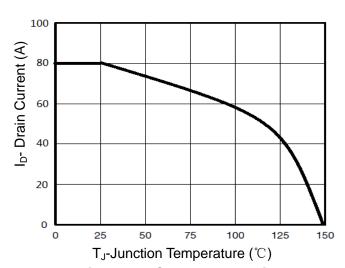


Figure 10 Current De-rating

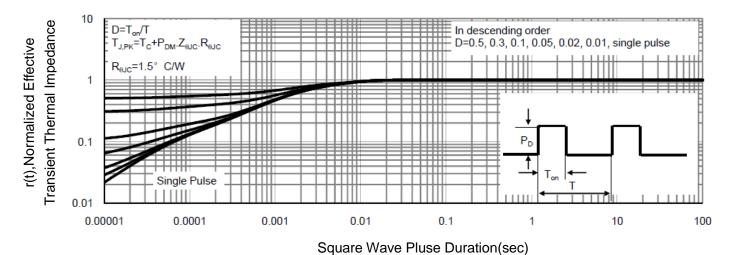


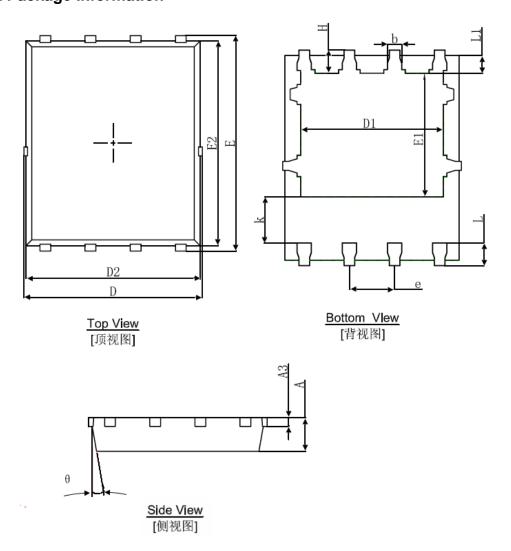
Figure 11 Normalized Maximum Transient Thermal Impedance

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Pb Free Product



DFN5X6-8L Package Information



C) male al	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
Α	0.900	1.000	0.035	0.039	
A3	0.254	REF.	0.010	REF.	
D	4.944	5.096	0.195	0.201	
E	5.974	6.126	0.235	0.241	
D1	3.910	4.110	0.154	0.162	
E1	3.375	3.575	0.133	0.141	
D2	4.824	4.976	0.190	0.196	
E2	5.674	5.826	0.223	0.229	
k	1.190	1.390	0.047	0.055	
b	0.350	0.450	0.014	0.018	
е	1.270	TYP.	0.050	YP.	
L	0.559	0.711	0.022	0.028	
L1	0.424	0.576	0.017	0.023	
Н	0.574	0.726	0.023	0.029	
θ	8°	12°	8°	12°	



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